





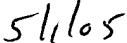


Form 1449 (Modified) Information Disclosure Statement By Applicant (Use Several Sheets if Necessary)	Atty Docket No.	Application No.:
	UNTYP019	10/604,606
	Applicant:	
	Rinerson et al.	
Filing Date	Group	
August 4, 2003	2813	

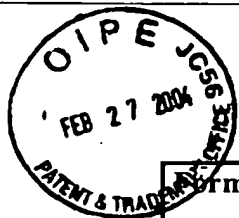
U.S. Patent Documents

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub- class	Filing Date
<i>pr</i>	A	6,204,139	2001-03-20	Liu et al.			

Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication			
	B	Basun, S. A. et al., " <i>Photoinduced Phenomena in $Sr_{1-x}CA_xTiO_2$, $0 \leq x \leq 0.12$</i> ", Ferroelectrics, Vol. 183, 1996,255-264.			
	C	Beck, A. et al., " <i>Reproducible switching effect in thin oxide films for memory applications</i> ", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000,139-141.			
	D	Gerstner E.G. et al., " <i>Nonvolatile memory effects in nitrogen doped tetrahedral amorphous carbon thin films</i> ", Journal of Applied Physics, Vol. 84, No. 10, 15 November 1998, 5647-5651.			
	E	Koidl, P. et al., " <i>Photochromism in Ni-doped $SrTiO_3$</i> ", Physical Review B, Vol. 14, No. 7, 1 October 1976, 2703-2708.			
	F	Rossel, C. et al., " <i>Electrical current distribution across a metal-insulator-metal structure during bistable switching</i> ", Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.			
	G	Watanabe, Y. et al., " <i>Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped $SrTiO_3$ single crystals</i> ", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.			
Examiner			Date Considered		

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Other Documents

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<i>RS</i>	A	Liu, S.Q., et al., "Electric-pulse-induced reversible resistance change effect in magnetoresistive films", Applied Physics Letters, Vol. 76, No. 19, 8 May 2000, 2749-2651.
<i>RS</i>	B	Liu, S.Q., et al., "A New Concept For Non-Volatile Memory: Electric-Pulse Induced Reversible Resistance Change Effect In Magnetoresistive Films", Space Vacuum Epitaxy Center, University of Huston, Huston TX, 7 Pages.
		<i>/</i> <i>/</i>
Examiner	<i>RS</i>	Date Considered <i>5/1/05</i>

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.